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To:	Examiner George P. Wyszomierski Art Unit: 1742	From:	Leslie S. Szivos
Fax:	571-273-8300	Pages:	14 pages including fax cover sheet
Phone	•	Date:	11/21/2005
Re:	U.S. Patent Appln. No. 10/662,028 Docket: YOR920030203US1 (16694) Confirmation No. 9297	CC:	

RESPONSE TO OFFICE ACTION

Please see the following documents:

- 1. Amendment Transmittal (in duplicate)
- 2. Authorization to charge IBM deposit account
- 3. Response under 37 C.F.R. § 1.111
- 4. Certificate of transmission by facsimile dated November 21, 2005

If you have any questions concerning this facsimile please contact Vivian Henriquez at 516-742-4343. Thank you.

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	TRANSMISSION BY FAC	SIMILE (37 CFR 1.8)	YO	Docket No. 0R920030203US1 (16694)	
Application No. 10/662,028	Filing Date September 12, 2003	Examiner George P. Wyszomiersk	Group Art Unit		
	N OF A SILICON GERMANIUI ROUS SILICON LAYER (As A		URE B	Y OXIDATION	
I hereby certify that this	Re	esponse Under 37 C.F.R. § 1.11	1 _		
		(Identify type of correspondence)			
is being facsimile transm	itted to the United States Patent	and Trademark Office (Fax. N	No. <u>57</u>	1-273-8300	
on November 2	1 200E				
On November 2 (Date)	1, 2005				
	•	Leslie S. Zzív)	Ld¶\zd). /	
		(Typed or Printed Name of Person			
			Y		
		(Signature	<u></u> <u>!</u>)		
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	Note: Each paper must ha	ve its own certificate of mailing.			
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AMENDMENT TRANSMITTAL LETTER (Large Entity)						Docket No.			
Applicant(s): Stephen W. Bedell et al.				YOR920030203US1 (16694)					
Application No.	Filing Date	Examiner	Custome	r No.	Group Art Uni	t Confirmation No.			
10/662,028	September 12, 2003	George P. Wyszomie	rski 2338	9	1742	9297			
Invention: FOR	MATION OF A SILIC	ON GERMANIUM-ON	-INSULATOR ST	RUC'	TURE BY OXI	DATION OF A			
I machilloti.	Invention: FORMATION OF A SILICON GERMANIUM-ON-INSULATOR STRUCTURE BY OXIDATION OF A BURIED POROUS SILICON LAYER (As Amended)								
	COMMISSIONER FOR PATENTS:								
Transmitted herew	vith is an amendment i	n the above-identified a	pplication.						
The fee has been	calculated and is trans	smitted as shown below							
		CLAIMS AS AM	ENDED						
	CLAIMS REMAINING	HIGHEST #	NUMBER EXTRA			ADDITIONAL			
	AFTER AMENDMENT	PREV. PAID FOR	CLAIMS PRESENT		RATE	FEE			
TOTAL CLAIMS	36 -	36 =	0 .	x	\$50.00	\$0.00			
INDEP. CLAIMS	2 -	3 =	0	х	\$200.00	\$0.00			
Multiple Dependen	Multiple Dependent Claims (check if applicable)								
		TOTAL ADDITIONAL	FEE FOR THIS A	MEN	OMENT	\$0.00			
☑ No addition	nal fee is required for	amendment.							
	arge Deposit Account		n the amount of						
	the amount of	to cover the filing							
		d to charge payment of			ciated with this	5			
	•	erpayment to Deposit Acquired under 37 C.F.R.		IRM					
	_	essing fees under 37 C							
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WARNING	: Information on this	form may become pu	blic. Credit card	infor	mation shoul	d not be			
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1	X		Datad: Navom	hor 7	1 2005				
1	Signature		Dated: Novem	ber 2	1, 2005				
Leslie S. Szivos, Pi	Signature h.D.		Dated: Novem	ber 2	1, 2005				
Registration No. 3	h.D. 9,394		I hereby certify th	at this	correspondence	is being deposited with			
Registration No. 3 SCULLY, SCOTI	h.D. 9,394 r, MURPHY & PRESS	ER	I hereby certify the United States	at this	correspondence	fficient postage as first			
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Registration No. 3 SCULLY, SCOTT 400 Garden City I	h.D. 9,394 I, MURPHY & PRESS Plaza - Suite 300	ER	I hereby certify the United States class had in an en P.O. Box 1450, Ale	at this Posta	correspondence I Service with su addressed to "Co	fficient postage as first mmissioner for Patents,			
Registration No. 3 SCULLY, SCOTT 400 Garden City I	h.D. 9,394 I, MURPHY & PRESS Plaza - Suite 300	ER	I hereby certify the United States class hail in an en	at this Posta	correspondence I Service with su addressed to "Co	fficient postage as first mmissioner or Patents,			
Registration No. 3 SCULLY, SCOTT 400 Garden City I	h.D. 9,394 I, MURPHY & PRESS Plaza - Suite 300	ER	I hereby certify the United States class had in an en P.O. Box 1450, Ale	at this Posta	correspondence I Service with su addressed to "Co	fficient postage as first mmissioner or Patents,			
Registration No. 3 SCULLY, SCOTT 400 Garden City I	h.D. 9,394 I, MURPHY & PRESS Plaza - Suite 300	ER	I hereby certify the United States class had in an en P.O. Box 1450. Ale	at this Posta velope xandri	correspondence I Service with su addressed to "Co	fficient postage as first mmissioner of Patents, [37 Chr 1.8(a)] on			

AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Stephen W. Bedell et al.					Docket No. YOR920030203US1 (16694)			
Application No. 10/662,028			No.	Group Art Unit 1742	Confirmation No. 9297			
Invention: FORMATION OF A SILICON GERMANIUM-ON-INSULATOR STRUCTURE BY OXIDATION OF A BURIED POROUS SILICON LAYER (As Amended)								
COMMISSIONER FOR PATENTS: Transmitted herewith is an amendment in the above-identified application.								
The fee has been	calculated and is trans	mitted as shown below	•					
		CLAIMS AS AM	ENDED) 				
	CLAIMS REMAINING	HIGHEST #	NUMBI	ER EXTRA		RATE	ADDITIONAL	
	AFTER AMENDMENT	PREV. PAID FOR	CLAIMS	CLAIMS PRESENT			FEE	
TOTAL CLAIMS	36 -	36 =		0	×	\$50.00	\$0.00	
INDEP. CLAIMS	2 -	3 =		0	X	\$200.00	\$0.00	
Multiple Depender	Multiple Dependent Claims (check if applicable)							
		TOTAL ADDITIONAL I	FEE FO	R THIS AM	END	DMENT	\$0.00	
No additional fee is required for amendment. Please charge Deposit Account No. in the amount of A check in the amount of to cover the filing fee is enclosed. The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account 50-0510/IBM Any additional filing fees required under 37 C.F.R. 1.16. Any patent application processing fees under 37 CFR 1.17. Payment by credit card. Form PTO-2038. WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.								
	Signature Dated: November 21, 2005							
Leslie S. Szivos, Ph.D. Registration No. 39,394 SCULLY, SCOTT, MURPHY & PRESSER 400 Garden City Plaza - Suite 300 Garden City, New York 11530 I hereby certify that this correspondence is being deposited with the Daited States Postal Service with sufficient postage as first class mail in an envelope addressed to "Commissioner for Patents P.O. Box 1450, Alexandria, VA 22313-1450" [37 CFD 4.8(a)] on (Date) Signature of Person Mailing Correspondence								
cc:						ne of Person Malling		

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Stephen W. Bedell, et al. Examiner: George P. Wyszomierski

Serial No.: 10/662,028 Art Unit: 1742

Filed: September 12, 2003 Docket: YOR920030203US1 (16694)

For: FORMATION OF A SILICON

Date: November 21, 2005

GERMANIUM-ON-INSULATOR STRUCTURE BY OXIDATION OF A BURIED POROUS SILICON LAYER

(As Amended)

Confirmation No: 9297

Mailstop Amendment Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

RESPONSE UNDER 37 C.F.R. § 1.111

Sir:

In response to the Office Action dated August 24, 2005, applicants submit the following amendments and remarks for entry of record in the above-identified patent application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this document is being filed in the United States Patent and Trademark Office on the date shown below via facsimile transmission to Mail Stop Amendment, Commissioner for Patents, PO Box 1450, Alexandria, VA 22313-1450 at United States Patent and Trademark Office facsimile transmission number (571) 273-8300.

Dated: November 21, 2005

Leslie S. Szivos, Ph.D.